# N-Channel 100-V (D-S) MOSFET

## **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

# ESD Protected

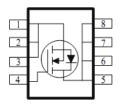
PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I⊳(A)	
100	78 @ V <sub>GS</sub> = 10V	5.2	
100	92 @ V <sub>GS</sub> = 4.5V	4.8	

# **Typical Applications:**

- PoE Power Sourcing Equipment
- PoE Powered Devices
- Telecom DC/DC converters
- · White LED boost converters







ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage			100	V	
Gate-Source Voltage	$V_{GS}$	±20	V		
Continuous Drain Current <sup>a</sup>	T <sub>A</sub> =25°C	L	5.2		
Continuous Drain Current	T <sub>A</sub> =70°C	l <sub>D</sub>	4.4	Α	
Pulsed Drain Current <sup>b</sup>	I <sub>DM</sub>	50			
Continuous Source Current (Diode Conduction) a	I <sub>S</sub>	3	Α		
Power Dissipation <sup>a</sup>	T <sub>A</sub> =25°C	$P_{D}$	3.1	W	
rower Dissipation	T <sub>A</sub> =70°C	' D	2.2	V V	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Maximum	Units	
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	$R_{\theta JA}$	40	°C/W	
Maximum Junction-to-Ambient	Steady State	IΛθJA	80	C/VV	

1

#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

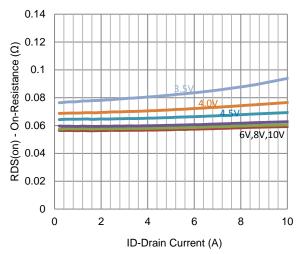
Parameter	Symbol Test Conditions		Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \text{ uA}$			3.5	V	
Gate-Body Leakage	I <sub>GSS</sub>	1 01/1/ 001/			±10	uA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Brain Gurrent	DSS	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	20			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_D = 3.6 \text{ A}$			78	mΩ	
Dialii-30dice Oil-Resistance	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 3.3 \text{ A}$			92	11152	
Forward Transconductance	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 3.6 \text{ A}$		20		S	
Diode Forward Voltage	$V_{SD}$	$I_{S} = 1.5 \text{ A}, V_{GS} = 0 \text{ V}$		0.7		V	
	Dynamic						
Total Gate Charge	$Q_g$			17.7			
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 50 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 3.6 \text{ A}$		2.7		nC	
Gate-Drain Charge	$Q_{gd}$			11.1			
Turn-On Delay Time	t <sub>d(on)</sub>			7			
Rise Time	t <sub>r</sub>	$V_{DD} = 50 \text{ V}, R_L = 13.9 \Omega, I_D = 3.6 \text{ A},$ $V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		5.8		ns	
Turn-Off Delay Time	$t_{d(off)}$			46		115	
Fall-Time	t <sub>f</sub>			26			
Input Capacitance	$C_{iss}$			990			
Output Capacitance	C <sub>oss</sub>	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		115		pF	
Reverse Transfer Capacitance C <sub>rss</sub>				77			

#### Notes

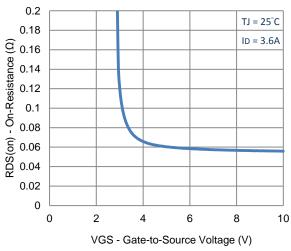
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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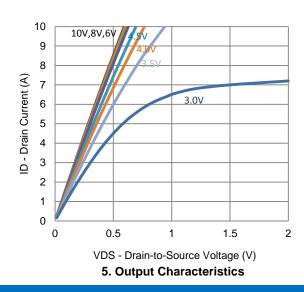
## **Typical Electrical Characteristics**

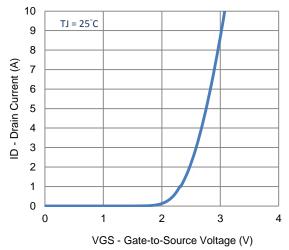


#### 1. On-Resistance vs. Drain Current

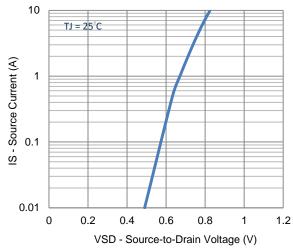


3. On-Resistance vs. Gate-to-Source Voltage

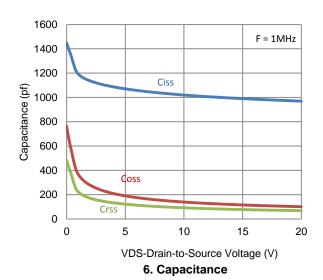




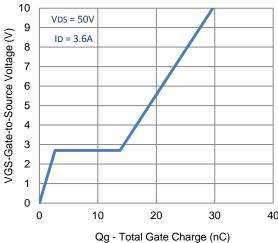
2. Transfer Characteristics



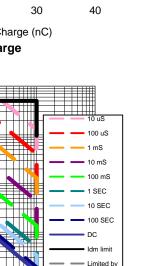
4. Drain-to-Source Forward Voltage



## **Typical Electrical Characteristics**





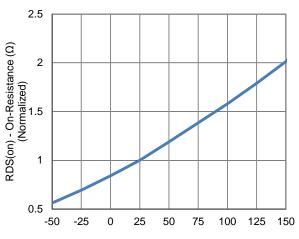


1000

10 VDS Drain to Source Voltage (V)

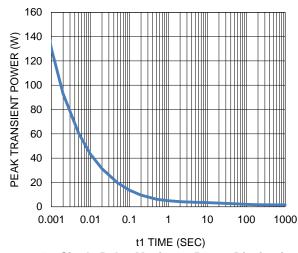
100

#### 9. Safe Operating Area

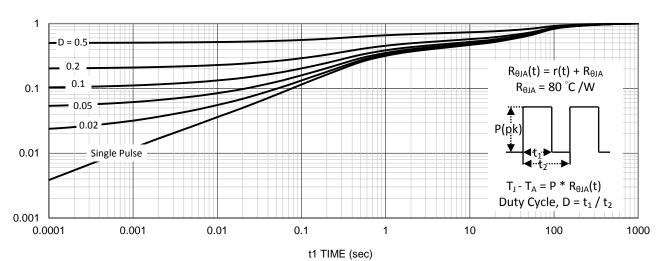


TJ - Junction Temperature (°C)

### 8. Normalized On-Resistance Vs **Junction Temperature**



10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

100

10

0.1

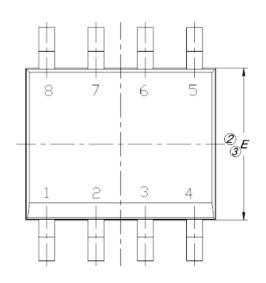
0.01

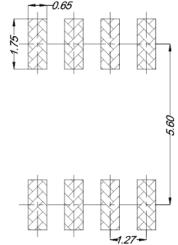
0.1

ID Current (A)

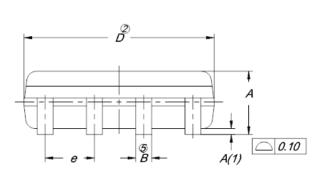
## **Package Information**

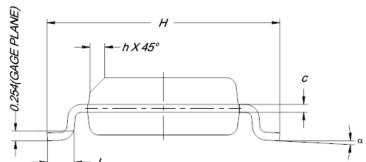
Land Pattern (Only for Reference)





DIM.	MILLIMETERS				
	MIN.	NOM.	MAX.		
Α	1.35	1.55	1.75		
A(1)	0.10	0.18	0.25		
В	0.38	0.45	0.51		
С	0.19	0.22	0.25		
D	4.80	4.90	5.00		
E	3.80	3.90	4.00		
е	1.27 BSC				
Н	5.80	6.00	6.20		
L	0.50	0.72	0.93		
α	0°	4°	8°		
h	0.25	0.38	0.50		





#### Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.
- Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Tie Bar Burrs, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.
- 4. The Package Top May Be Smaller Than The Package Bottom.
- 5. Dimension B" Does Not Include Dambar Protrusion. Allowable Dambar Protrusion Shall Be 0.08 mm Total In Excess Of B" Dimension At Maximum Material Condition. The Dambar Cannot Be Located On The Lower Radius Of The Foot.